

#### Description

The AON1605 uses advanced trench technology to provide excellent  $R_{\rm DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

# DFN1006-3L

DFN1006-3L (DFN-3(0.6x1))

# G S

P-Channel MOSFET

#### **General Features**

 $V_{DS} = -20V I_{D} = -0.8A$ 

 $R_{DS(ON)} < 560 \text{ m}\Omega@V_{GS} = -4.5V$ 

 $R_{DS(ON)}$  < 780 mQ@  $V_{GS}$ =-2.5V

ESD Rating: 1500V HBM

### **Application**

**Battery protection** 

Load switch

Uninterruptible power supply

# **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
AON1605	DFN1006-3L(DFN-3(0.6x1))	HXY MOSFET	10000

# Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Limit	Unit	
Drain-Source Voltage	-20	V	
Gate-Source Voltage	±12	V	
Drain Current-Continuous	-0.8	Α	
Maximum Power Dissipation	100	mW	
Operating Junction and Storage Temperature Range	-55 To 150	$^{\circ}$	
Thermal Resistance,Junction-to-Ambient (Note 2)	1250	°C/W	
-	Drain-Source Voltage  Gate-Source Voltage  Drain Current-Continuous  Maximum Power Dissipation  Operating Junction and Storage Temperature Range	Drain-Source Voltage -20  Gate-Source Voltage ±12  Drain Current-Continuous -0.8  Maximum Power Dissipation 100  Operating Junction and Storage Temperature Range -55 To 150	



#### $T_a=25$ °C unless otherwise noted

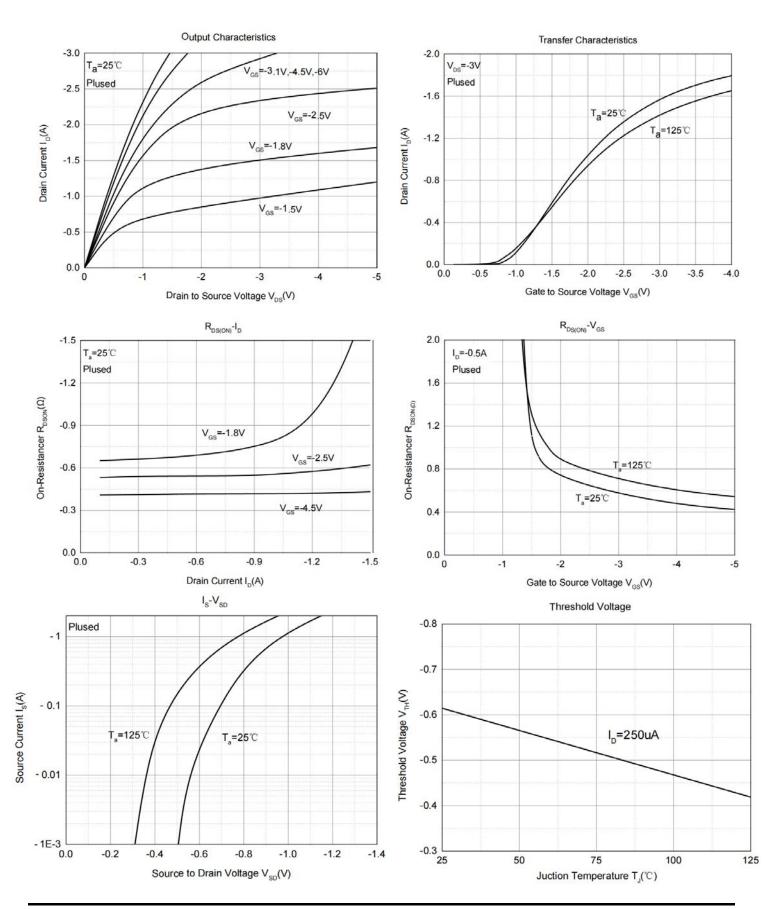
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
STATIC PARAMETERS							
Drain-source breakdown voltage	V(BR)DSS	V <sub>G</sub> S = 0V, I <sub>D</sub> =-250µA	-20			V	
Zero gate voltage drain current	Inss	V <sub>DS</sub> =-20V,V <sub>GS</sub> = 0V			-1	μA	
Gate-body leakage current	Igss	V <sub>GS</sub> =±10V, V <sub>DS</sub> = 0V			±20	uA	
Gate threshold voltage (note 2)	VGS(th)	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250µA	-0.35	-0.61	-1.1	V	
		V <sub>G</sub> S =-4.5V, I <sub>D</sub> =-1A		350	390	mΩ	
Drain-source on-resistance(note 2)	RDS(on)	V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-0.8A		395	460	mΩ	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-0.5A		450		mΩ	
Forward tranconductance(note 2)	grs	V <sub>DS</sub> =-10V, I <sub>D</sub> =-0.54A		1.2		S	
Diode forward voltage	V <sub>SD</sub>	I <sub>S</sub> =-0.5A, V <sub>GS</sub> = 0V			-1.2	V	
DYNAMIC PARAMETERS(note 4)							
Input Capacitance	C <sub>iss</sub>			113		pF	
Output Capacitance	Coss	V <sub>DS</sub> =-16V,V <sub>GS</sub> =0V,f =1MHz		15		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	ss		9		pF	
SWITCHING PARAMETERS (note 4)							
Turn-on delay time (note 3)	td(on)			9		ns	
Turn-on rise time (note 3)	tr	V <sub>DD</sub> =-4.5V,V <sub>GS</sub> =-10V,		5.7		ns	
Turn-off delay time (note 3)	t <sub>d(off)</sub>	$I_D$ =-200mA, $R_{GEN}$ =10 $\Omega$		32.6		ns	
Turn-off fall time (note 3)	<b>t</b> f			20.3		ns	

#### Notes:

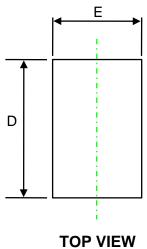
- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test: Pulse Width=300µs, Duty Cycle=2%.
- 3. Switching characteristics are independent of operating junction temperatures.
- 4. Guaranteed by design, not subject to producting.

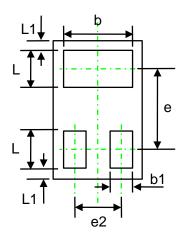


## **Typical Electrical**

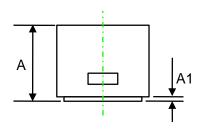


# DFN1006-3L(DFN-3(0.6x1)) Package Outline Dimensions





IEW BOTTOM VIEW



**SIDE VIEW** 

Symbol	Dimensions In Millimeters (mm)			
	Min.	Тур.	Max.	
А	0.44	0.47	0.50	
A1	0.00	0.03	0.05	
D	0.95	1.00	1.05	
E	0.55	0.60	0.65	
b	0.45	0.50	0.55	
е	-	0.65	-	
e2	-	0.35	-	
L1		0.05 REF.		
L	0.20	0.25	0.30	
b1	0.10	0.15	0.20	



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